

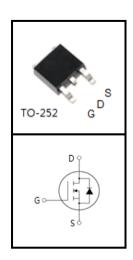
600V N-Channel MOSFET

FEATURES

- Fast switching
- 100% avalanche tested
- Improved dv/dt capability

APPLICATIONS

- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply (UPS)
- Power Factor Correction (PFC)



Device Marking and Package Information			
Device	Package	Marking	
CS1N60D	TO-252	CS1N60D	

Absolute Maximum Ratings $T_C = 25^{\circ}C$, unless otherwise noted			
Parameter	Symbol	Value	Unit
Drain-Source Voltage (V _{GS} = 0V)	V _{DSS}	600	V
Continuous Drain Current	I _D	1.3	Α
Pulsed Drain Current (note1)	I _{DM}	5.2	А
Gate-Source Voltage	V _{GSS}	±30	V
Single Pulse Avalanche Energy (note2)	E _{AS}	7.2	mJ
Avalanche Current (note1)	I _{As}	1.2	Α
Repetitive Avalanche Energy (note1)	E _{AR}	0.029	mJ
Power Dissipation (T _C = 25°C)	P _D	27.5	W
Operating Junction and Storage Temperature Range	T _J , T _{stg}	-55~+150	°C

Thermal Resistance			
Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case	R _{thJC}	4.53	00044
Thermal Resistance, Junction-to-Ambient	R _{thJA}	105	°C/W



Specifications $T_J = 25^{\circ}C$, ur	less other	rwise noted				
Parameter	Symbol	Test Conditions	Value			Unit
	Symbol	rest conditions	Min.	Тур.	Max.	Offic
Static						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	600			٧
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 600V, V_{GS} = 0V, T_{J} = 25^{\circ}C$			1	μΑ
Gate-Source Leakage	I _{GSS}	$V_{GS} = \pm 30V$			±100	nA
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	3.0		4.2	V
Drain-Source On-Resistance (Note3)	R _{DS(on)}	$V_{GS} = 10V, I_{D} = 0.5A$		7.0	8.0	Ω
Dynamic						
Input Capacitance	C _{iss}	V 0V		131		pF
Output Capacitance	C _{oss}	$V_{GS} = 0V,$ $V_{DS} = 25V,$		16.5		
Reverse Transfer Capacitance	C _{rss}	f = 1.0MHz		2.5		
Total Gate Charge	Q_g			6.3		nC
Gate-Source Charge	Q_{gs}	$V_{DD} = 480V, I_{D} = 1.3A,$ $V_{GS} = 10V$		0.8		
Gate-Drain Charge	Q_{gd}	65		4.2		
Turn-on Delay Time	t _{d(on)}	V _{DD} = 300V, I _D =1.3A,		32.5		
Turn-on Rise Time	t _r			6.5		ns
Turn-off Delay Time	$t_{d(off)}$	$R_G = 25 \Omega$		42.5		
Turn-off Fall Time	t _f			43		
Drain-Source Body Diode Character	istics					
Continuous Body Diode Current	Is	T 0500			1.3	Α
Pulsed Diode Forward Current	I _{SM}	T _C = 25 °C			5.2	
Body Diode Voltage	V _{SD}	$T_J = 25^{\circ}C$, $I_{SD} = 0.5A$, $V_{GS} = 0V$			1.4	V
Reverse Recovery Time	t _{rr}	$V_{DD} = 300V, I_{S} = 1.3A,$		3.8		ns
Reverse Recovery Charge	Q _{rr}	di _F /dt =100A /μs		0.53		μC

Notes

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature
- 2. L=10mH, V_{DD} = 50V, R_G = 25 Ω , Starting T_J = 25 $^{\circ}C$
- 3. Pulse Test: Pulse width ≤ 300µs, Duty Cycle ≤ 1%



Typical Characteristics $T_J = 25^{\circ}\text{C}$, unless otherwise noted

Figure 1. Output Characteristics ($T_J = 25^{\circ}C$)

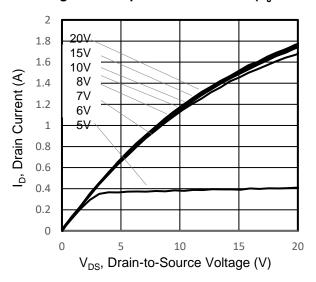


Figure 3. Drain Current vs. Temperature

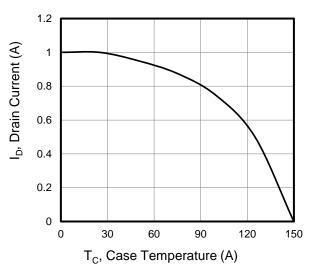


Figure 5. Transfer Characteristics

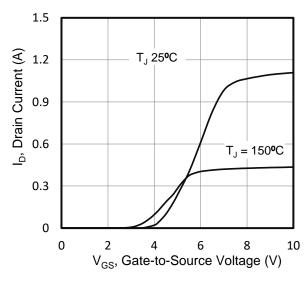


Figure 2. Body Diode Forward Voltage

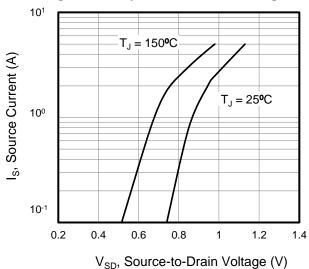


Figure 4. BV_{DSS} Variation vs. Temperature

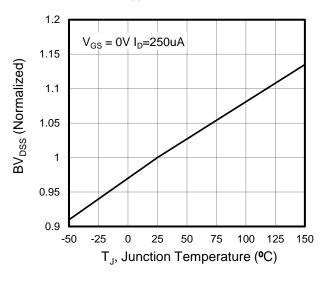
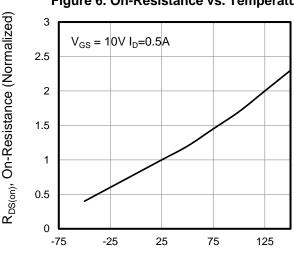
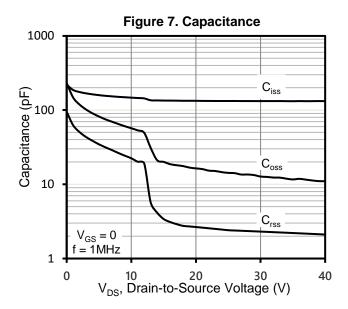


Figure 6. On-Resistance vs. Temperature





Typical Characteristics $T_J = 25^{\circ}\text{C}$, unless otherwise noted



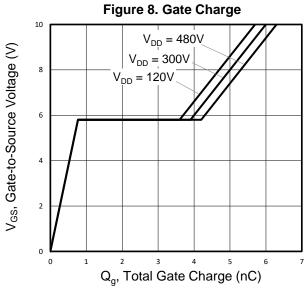


Figure 9. Transient Thermal Impedance

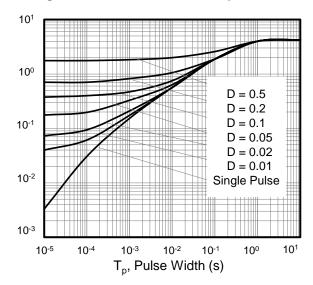




Figure A: Gate Charge Test Circuit and Waveform

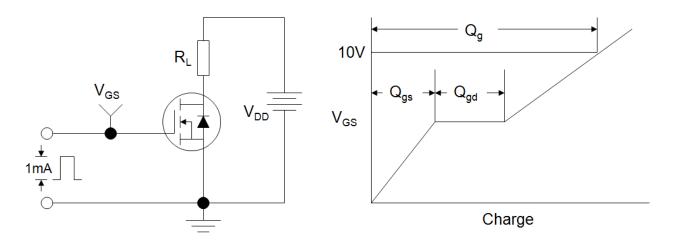


Figure B: Resistive Switching Test Circuit and Waveform

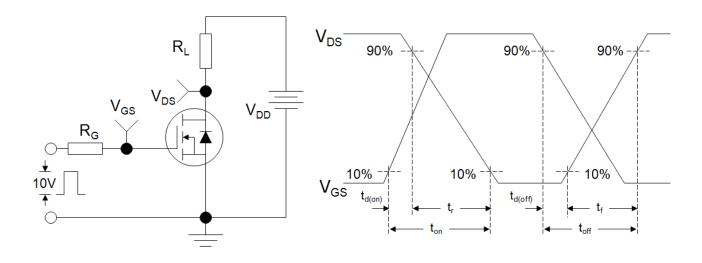
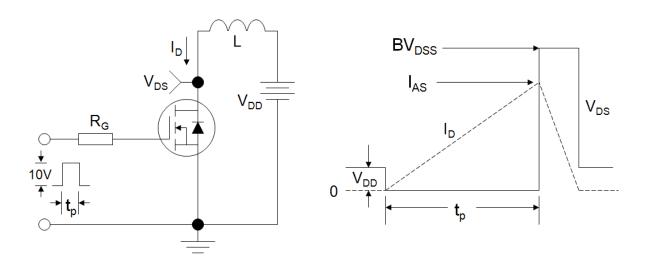
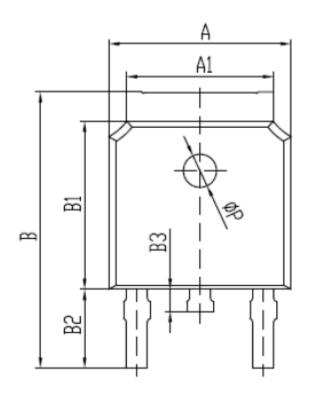


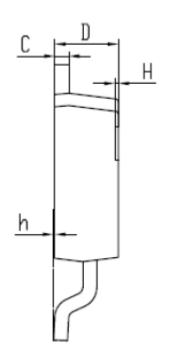
Figure C: Unclamped Inductive Switching Test Circuit and Waveform

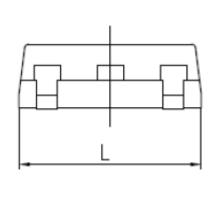


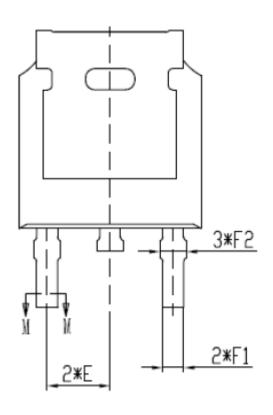


TO-252









CVMADOLC	MILLIMETERS		
SYMBOLS	MIN	MAX	
Α	6.50	6.70	
A1	5.16	5.46	
В	9.77	10.17	
B1	6.00	6.20	
B2	2.60	3.00	
В3	0.70	0.90	
С	0.45	0.61	
D	2.20	2.40	
E	2.19	2.39	
F1	0.67	0.87	
F2	0.76	0.96	
Н	0.00	0.30	
h	0.00	0.13	
L	6.50	6.70	
ФР	1.10	1.30	



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